# 22639

## 23242 3 Hours / 70 Marks

Seat No.				
Scat NO.				

#### *Instructions*: (1) All Questions are *compulsory*.

- (2) Illustrate your answers with neat sketches wherever necessary.
- (3) Figures to the right indicate full marks.
- (4) Assume suitable data, if necessary.
- (5) Mobile Phone, Pager and any other Electronic Communication devices are not permissible in Examination Hall.

		Marks
1.	Attempt any FIVE of the following :	10
	(a) Define clock skew. State causes of clock skew (any <b>two</b> ).	

- (b) State ways to reduce the metastability (any **four**).
- (c) State the rules for using identifiers in VHDL (any **four**).
- (d) Define test bench with the help of suitable example.
- (e) Enlist two VHDL statements which are used to define sensitivity list.
- (f) Define concept of Event Scheduling. State types of events involved in event scheduling.
- (g) Draw NAND gate using CMOS.

#### 2. Attempt any THREE of the following :

- (a) With the help of suitable diagram explain ASIC design flow.
- (b) Write a VHDL program for BCD to seven segment converter using When-Else statement.



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(c)	Compare software	description	language and	hardware	description	language
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(d) Differentiate between CMOS technology and BJT.

#### 3. Attempt any THREE of the following :

- (a) Draw general architecture of FPGA. State function of each block in it.
- (b) Write a short note on Architecture in VHDL program. Give one example of it.
- (c) Explain various operators used in VHDL.
- (d) Write VHDL program for 4 : 1 multiplexer using CASE statement.

#### 4. Attempt any THREE of the following :

- (a) Differentiate between FPGA and CPLD.
- (b) Explain delays in simulation with suitable example.
- (c) Explain process of resistance estimation for CMOS.
- (d) Explain nMOS fabrication process with the help of suitable diagram.
- (e) Define following terms with respect to CMOS fabrication :
  - (i) Wafer Processing (ii) Oxidation
  - (iii) Ion implementation (iv) Diffusion

#### 5. Attempt any TWO of the following :

- (a) Differentiate between Melay Machine and Moore Machine (any six points).
- (b) Write a VHDL program for 2 : 4 decoder. Also write a test bench for it.
- (c) Design following function using CMOS logic

### $Z = \overline{(A \cdot B + \overline{C} \cdot D) + E}$

#### 6. Attempt any TWO of the following :

- (a) Design sequence detector to detect sequence '1011' using 'D' flip-flop.
- (b) Differentiate between signals, variable and constants in VHDL (any **four** points).
- (c) Explain simulation cycle with the help of suitable diagram. State function of event queue and evaluation queue in it.

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